

74ABT16646

16-Bit Transceivers and Registers with 3-STATE Outputs

General Description

The ABT16646 consists of bus transceiver circuits with 3-STATE, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a high logic level. Control $\overline{OE}$ and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control $\overline{OE}$ is Active LOW. In the isolation mode (control $\overline{OE}$ HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

Features

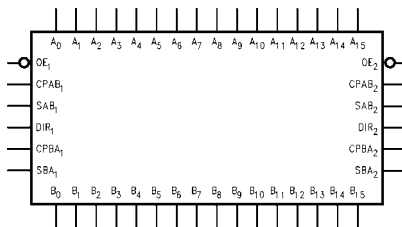
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

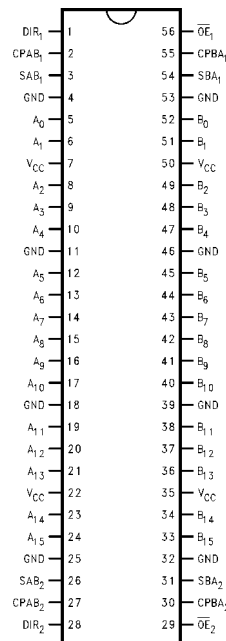
Order Number	Package Number	Package Description
74ABT16646CSSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT16646CMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A ₀ -A ₁₅	Data Register A Inputs/ 3-STATE Outputs
B ₀ -B ₁₅	Data Register B Inputs/ 3-STATE Outputs
CPAB _n , CPBA _n	Clock Pulse Inputs
SAB _n , SBA _n	Select Inputs
$\overline{OE}_n$	Output Enable Input
DIR	Direction Control Input

Function Table

Inputs						Data I/O (Note 1)		Output Operation Mode
$\overline{OE}_1$	DIR ₁	CPAB ₁	CPBA ₁	SAB ₁	SBA ₁	A ₀₋₇	B ₀₋₇	
H	X	H or L	H or L	X	X	Input	Input	Isolation
H	X	↗	X	X	X			Clock An Data into A Register
H	X	X	↗	X	X			Clock Bn Data Into B Register
L	H	X	X	L	X	Input	Output	An to Bn—Real Time (Transparent Mode)
L	H	↗	X	L	X			Clock An Data to A Register
L	H	H or L	X	H	X			A Register to Bn (Stored Mode)
L	H	↗	X	H	X			Clock An Data into A Register and Output to Bn
L	L	X	X	X	L	Output	Input	Bn to An—Real Time (Transparent Mode)
L	L	X	↗	X	L			Clock Bn Data into B Register
L	L	X	H or L	X	H			B Register to An (Stored Mode)
L	L	X	↗	X	H			Clock Bn into B Register and Output to An

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

↗ = LOW-to-HIGH Transition

Note 1: The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the appropriate clock inputs. Also applies to data I/O (A and B: 8-15) and #2 control pins.

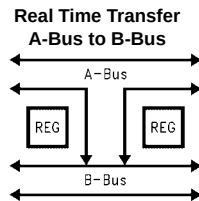


FIGURE 1.

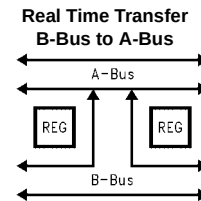


FIGURE 2.

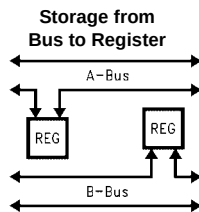


FIGURE 3.

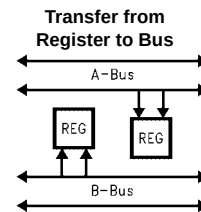
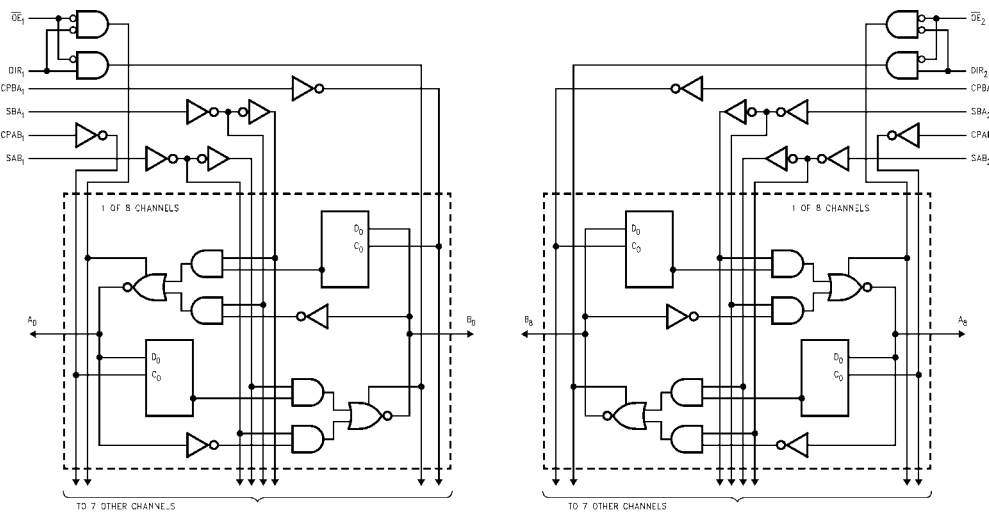


FIGURE 4.

Logic Diagram



Absolute Maximum Ratings(Note 2)

Storage Temperature	–65°C to +150°C
Ambient Temperature under Bias	–55°C to +125°C
Junction Temperature under Bias	–55°C to +150°C
V _{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
Input Voltage (Note 3)	–0.5V to +7.0V
Input Current (Note 3)	–30 mA to +5.0 mA
Voltage Applied to Any Output in the Disable or Power-Off State	–0.5V to +5.5V
in the HIGH State	–0.5V to V _{CC}
Current Applied to Output in LOW State (Max)	twice the rated I _{OL} (mA)
DC Latchup Source Current	–500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	–40°C to +85°C
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Typ	Max	Units	V _{CC}	Conditions
V _{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			–1.2	V	Min	I _{IN} = –18 mA (Non I/O Pins)
V _{OH}	Output HIGH Voltage	2.5 2.0					I _{OH} = –3 mA, (A _n , B _n) I _{OH} = –32 mA, (A _n , B _n)
V _{OL}	Output LOW Voltage			0.55	V	Min	I _{OL} = 64 mA, (A _n , B _n)
V _{ID}	Input Leakage Test	4.75			V	0.0	I _{ID} = 1.9 μ A, (Non-I/O Pins) All Other Pins Grounded
I _{IH}	Input HIGH Current			1 1	μ A	Max	V _{IN} = 2.7V (Non-I/O Pins) (Note 5) V _{IN} = V _{CC} (Non-I/O Pins)
I _{BVI}	Input HIGH Current Breakdown Test			7	μ A	Max	V _{IN} = 7.0V (Non-I/O Pins)
I _{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μ A	Max	V _{IN} = 5.5V (A _n , B _n)
I _{IL}	Input LOW Current			–1 –1	μ A	Max	V _{IN} = 0.5V (Non-I/O Pins) (Note 5) V _{IN} = 0.0V (Non-I/O Pins)
I _{IH} + I _{OZH}	Output Leakage Current			10	μ A	0V–5.5V	V _{OUT} = 2.7V (A _n , B _n); $\overline{\text{OE}}$ = 2.0V
I _{IL} + I _{OZL}	Output Leakage Current			–10	μ A	0V–5.5V	V _{OUT} = 0.5V (A _n , B _n); $\overline{\text{OE}}$ = 2.0V
I _{OS}	Output Short-Circuit Current	–100		–275	mA	Max	V _{OUT} = 0V (A _n , B _n)
I _{CEX}	Output HIGH Leakage Current			50	μ A	Max	V _{OUT} = V _{CC} (A _n , B _n)
I _{ZZ}	Bus Drainage Test			100	μ A	0.0V	V _{OUT} = 5.5V (A _n , B _n); All Others GND
I _{CCH}	Power Supply Current			1.0	mA	Max	All Outputs HIGH
I _{CCL}	Power Supply Current			60	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current			1.0	mA	Max	Outputs 3-STATE; All Others GND
I _{CCT}	Additional I _{CC} /Input			2.5	mA	Max	V _I = V _{CC} – 2.1V All Other Outputs at V _{CC} or GND
I _{CCD}	Dynamic I _{CC} (Note 5)	No Load		0.23	mA/ MHz	Max	Outputs OPEN $\overline{\text{OE}}$, DIR, and SEL = GND, Non-I/O = GND or V _{CC} (Note 4) One Bit toggling, 50% duty cycle

Note 4: For 8-bit toggling, I_{CCD} < 1.4 mA/MHz.

Note 5: Guaranteed but not tested.

DC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	Min	Typ	Max	Units	V _{CC}	Conditions C _L = 50 pF, R _L = 500Ω
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}		0.7	1.2	V	5.0	T _A = 25°C (Note 6)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-1.4	-1.0		V	5.0	T _A = 25°C (Note 6)
V _{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T _A = 25°C (Note 7)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.6		V	5.0	T _A = 25°C (Note 8)
V _{ILD}	Maximum LOW Level Dynamic Input Voltage		1.2	0.8	V	5.0	T _A = 25°C (Note 8)

Note 6: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.**Note 7:** Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.**Note 8:** Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.**AC Electrical Characteristics**

(SSOP Package)

Symbol	Parameter	T _A = +25°C V _{CC} = +5.0V C _L = 50 pF			T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 50 pF		Units
		Min	Typ	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency		200				MHz
t _{PLH}	Propagation Delay Clock to Bus	1.5	3.0	4.9	1.5	4.9	ns
t _{PHL}	Propagation Delay Bus to Bus	1.5	2.6	4.5	1.5	4.5	ns
t _{PLH}	Propagation Delay SBA _n or SAB _n to A _n to B _n	1.5	2.9	5.0	1.5	5.0	ns
t _{PHL}	Enable Time OE _n to A _n or B _n	1.5	3.0	5.5	1.5	5.5	ns
t _{PZH}	Disable Time OE _n to A _n or B _n	1.5	3.9	6.0	1.5	6.0	ns
t _{PZL}	Enable Time DIR _n to A _n or B _n	1.5	3.2	6.0	1.5	6.0	ns
t _{PHZ}	Disable Time DIR _n to A _n or B _n	1.5	3.8	6.5	1.5	6.5	ns
t _{PLZ}	Enable Time DIR _n to A _n or B _n	1.5	3.2	6.5	1.5	6.5	ns

AC Operating Requirements

Symbol	Parameter	T _A = +25°C V _{CC} = +5.0V C _L = 50 pF		T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 50 pF		Units
		Min	Max	Min	Max	
t _S (H) t _S (L)	Setup Time, HIGH or LOW Bus to Clock	2.0		2.0		ns
t _H (H) t _H (L)	Hold Time, HIGH or LOW Bus to Clock	1.0		1.0		ns
t _W (H) t _W (L)	Pulse Width, HIGH or LOW	3.0		3.0		ns

Extended AC Electrical Characteristics

(SSOP Package)

Symbol	Parameter	T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 50 pF 8 Outputs Switching (Note 9)		T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 250 pF 1 Output Switching (Note 10)		T _A = -40°C to +85°C V _{CC} = 4.5V–5.5V C _L = 250 pF 8 Outputs Switching (Note 11)		Units
		Min	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	1.5	5.8	2.0	7.5	2.5	10.0	ns
t _{PHL}	Clock to Bus	1.5	5.8	2.0	7.5	2.5	10.0	
t _{PLH}	Propagation Delay	1.5	6.5	2.0	7.0	2.5	9.5	ns
t _{PHL}	Bus to Bus	1.5	6.5	2.0	7.0	2.5	9.5	
t _{PLH}	Propagation Delay	1.5	6.0	2.0	7.5	2.5	10.0	ns
t _{PHL}	SBA _n or SAB _n to A _n or B _n	1.5	6.0	2.0	7.5	2.5	10.0	
t _{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	10.5	ns
t _{PZL}	$\overline{\text{OE}}_n$ to A _n or B _n	1.5	6.0	2.0	8.0	2.5	10.5	
t _{PHZ}	Output Disable Time	1.5	6.0	(Note 12)		(Note 12)		ns
t _{PLZ}	$\overline{\text{OE}}_n$ to A _n or B _n	1.5	6.0					
t _{PZH}	Output Enable Time	1.5	6.5	2.0	8.0	2.5	10.5	ns
t _{PZL}	DIR to A _n or B _n	1.5	6.5	2.0	8.0	2.5	10.5	
t _{PHZ}	Output Disable Time	1.5	6.5	(Note 12)		(Note 12)		ns
t _{PLZ}	DIR to A _n or B _n	1.5	6.5					

Note 9: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 10: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 12: The 3-STATE delays are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} - 5.5\text{V}$ $C_L = 50\text{ pF}$ 16 Outputs Switching (Note 13)	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} - 5.5\text{V}$ $C_L = 250\text{ pF}$ 16 Outputs Switching (Note 14)	Units
		Max	Max	
t_{OSHL} (Note 15)	Pin to Pin Skew HL Transitions	2.0	2.5	ns
t_{OSLH} (Note 15)	Pin to Pin Skew LH Transitions	2.0	2.5	ns
t_{PS} (Note 16)	Duty Cycle LH-HL Skew	2.0	2.5	
t_{OST} (Note 15)	Pin to Pin Skew LH/HL Transitions	2.8	3.0	ns
t_{PV} (Note 17)	Device to Device Skew LH/HL Transitions	3.5	4.0	ns

Note 13: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 14: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 15: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}). This specification is guaranteed but not tested.

Note 16: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

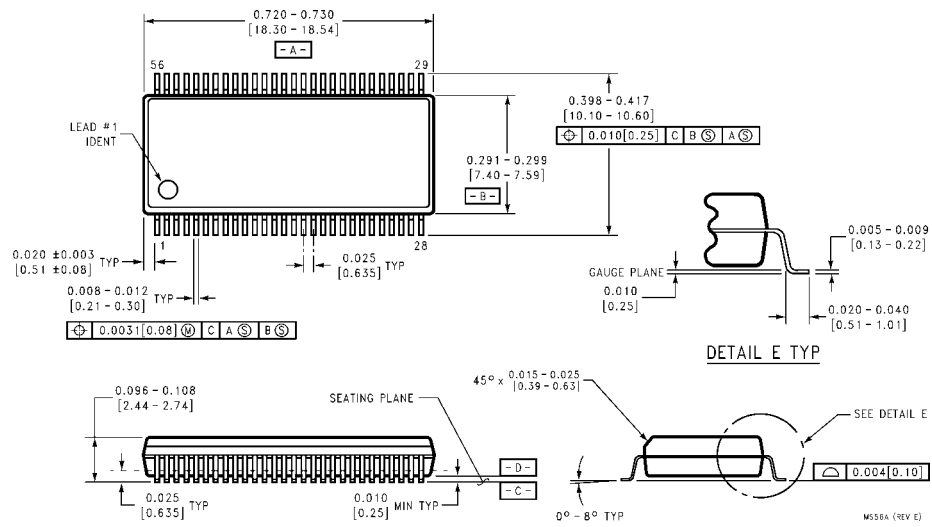
Note 17: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions $T_A = 25^{\circ}\text{C}$
C_{IN}	Input Capacitance	5	pF	$V_{CC} = 0\text{V}$ (non I/O pins)
$C_{I/O}$ (Note 18)	Output Capacitance	11	pF	$V_{CC} = 5.0\text{V}$ (A_n , B_n)

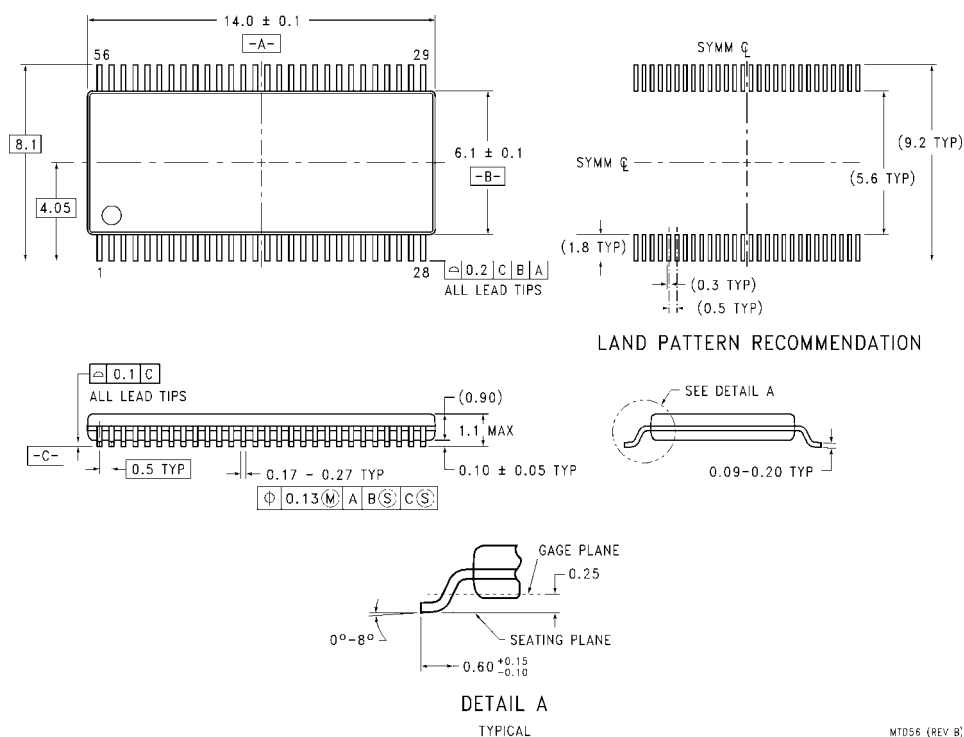
Note 18: $C_{I/O}$ is measured at frequency, $f = 1\text{ MHz}$, per MIL-STD-883, Method 3012.

Physical Dimensions inches (millimeters) unless otherwise noted



**56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
Package Number MS56A**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



**56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Package Number MTD56**

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